Renesas Electronics America Inc - M306N4MGT-152FPUTQ Datasheet

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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	M16C/60
Core Size	16-Bit
Speed	20MHz
Connectivity	CANbus, I²C, IEBus, SIO, UART/USART
Peripherals	DMA, WDT
Number of I/O	87
Program Memory Size	256KB (256K x 8)
Program Memory Type	Mask ROM
EEPROM Size	-
RAM Size	10K x 8
Voltage - Supply (Vcc/Vdd)	4.2V ~ 5.5V
Data Converters	A/D 26x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-BQFP
Supplier Device Package	100-QFP (14x20)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/m306n4mgt-152fputq

1.4 Product Information

Table 1.2 lists the Product Information and Figure 1.2 shows the Type Number, Memory Size, and Packages.

Table 1.2 Product Information As of Aug. 2006

Type No.	ROM Capacity	RAM Capacity	Package Type (2)	Remarks	
M306N4FCFP	128 K + 4 Kbytes	5 Kbytes	PRQP0100JB-A	Flash memory version (1)	Normal-ver.
M306N4FCGP			PLQP0100KB-A		
M306N4FGFP	256 K + 4 Kbytes	10 Kbytes	PRQP0100JB-A		
M306N4FGGP			PLQP0100KB-A		
M306N4FCTFP	128 K + 4 Kbytes	5 Kbytes	PRQP0100JB-A		T-ver.
M306N4FCTGP			PLQP0100KB-A		
M306N4FGTFP	256 K + 4 Kbytes	10 Kbytes	PRQP0100JB-A		
M306N4FGTGP			PLQP0100KB-A		
M306N4FCVFP	128 K + 4 Kbytes	5 Kbytes	PRQP0100JB-A		V-ver.
M306N4FCVGP			PLQP0100KB-A		
M306N4FGVFP	256 K + 4 Kbytes	10 Kbytes	PRQP0100JB-A		
M306N4FGVGP			PLQP0100KB-A		
M306N4MC-XXXGP	128 Kbytes	5 Kbytes	PLQP0100KB-A	Mask ROM version	Normal-ver.
M306N4MG-XXXGP	256 Kbytes	10 Kbytes	PLQP0100KB-A		
M306N4MCT-XXXFP	128 Kbytes	5 Kbytes	PRQP0100JB-A		T-ver.
M306N4MCT-XXXGP			PLQP0100KB-A		
M306N4MGT-XXXFP	256 Kbytes	10 Kbytes	PRQP0100JB-A		
M306N4MGT-XXXGP			PLQP0100KB-A		
M306N4MCV-XXXFP	128 Kbytes	5 Kbytes	PRQP0100JB-A		V-ver.
M306N4MCV-XXXGP (D)			PLQP0100KB-A		
M306N4MGV-XXXFP	256 Kbytes	10 Kbytes	PRQP0100JB-A		
M306N4MGV-XXXGP (D)			PLQP0100KB-A		

(D): Under development

NOTES:

1. Data flash memory provides an additional 4 Kbytes of ROM capacity (block A).
2. The correspondence between new and old package types is as follows.
   PRQP0100JB-A: 100P6S-A
   PLQP0100KB-A: 100P6Q-A

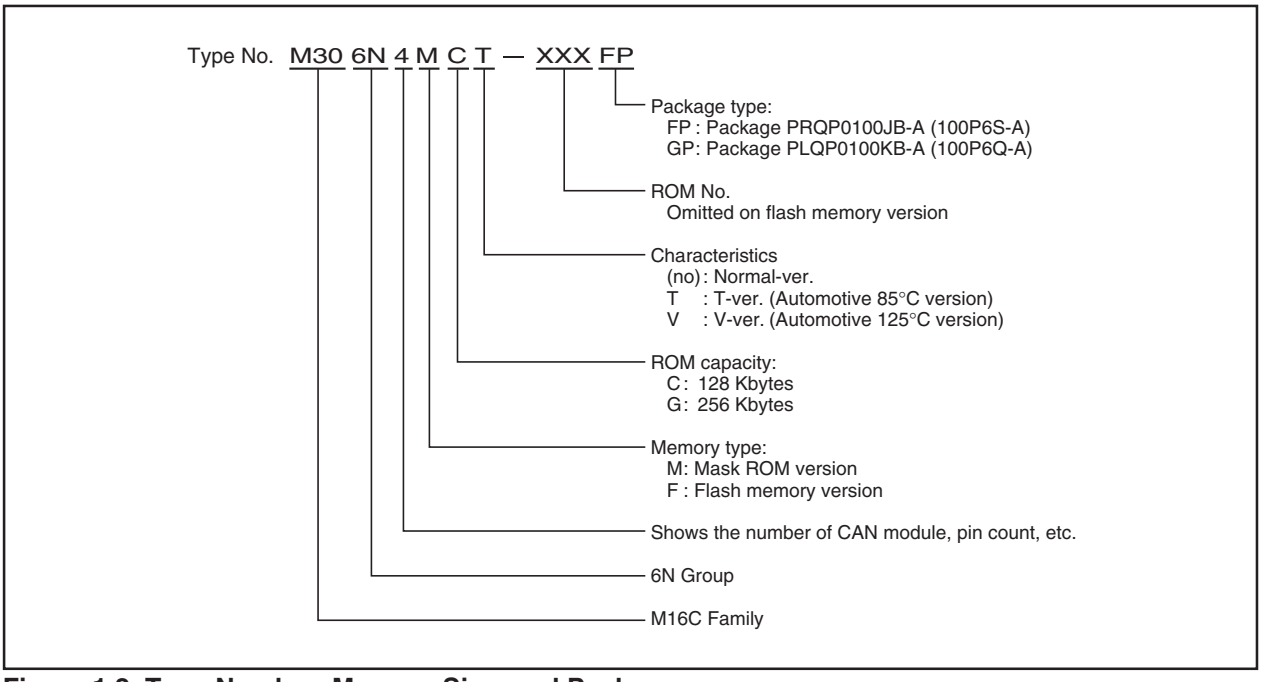
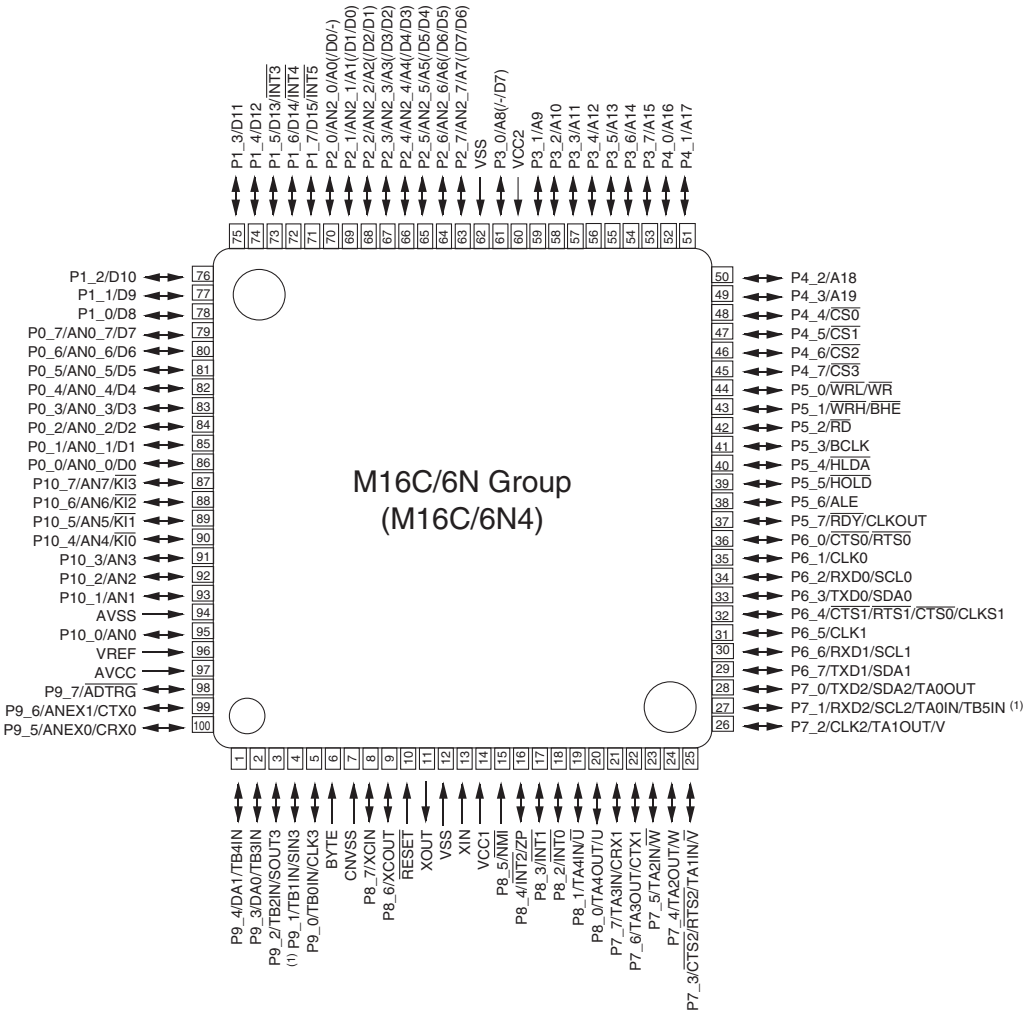


Figure 1.2 Type Number, Memory Size, and Package



NOTE: Package: PLQP0100KB-A (100P6Q-A)

1. P7_1 and P9_1 are N channel open-drain pins.

Figure 1.4 Pin Assignments (Top View) (2)

2. Central Processing Unit (CPU)

Figure 2.1 shows the CPU Registers. The CPU has 13 registers. Of these, R0, R1, R2, R3, A0, A1, and FB configure a register bank. There are two register banks.

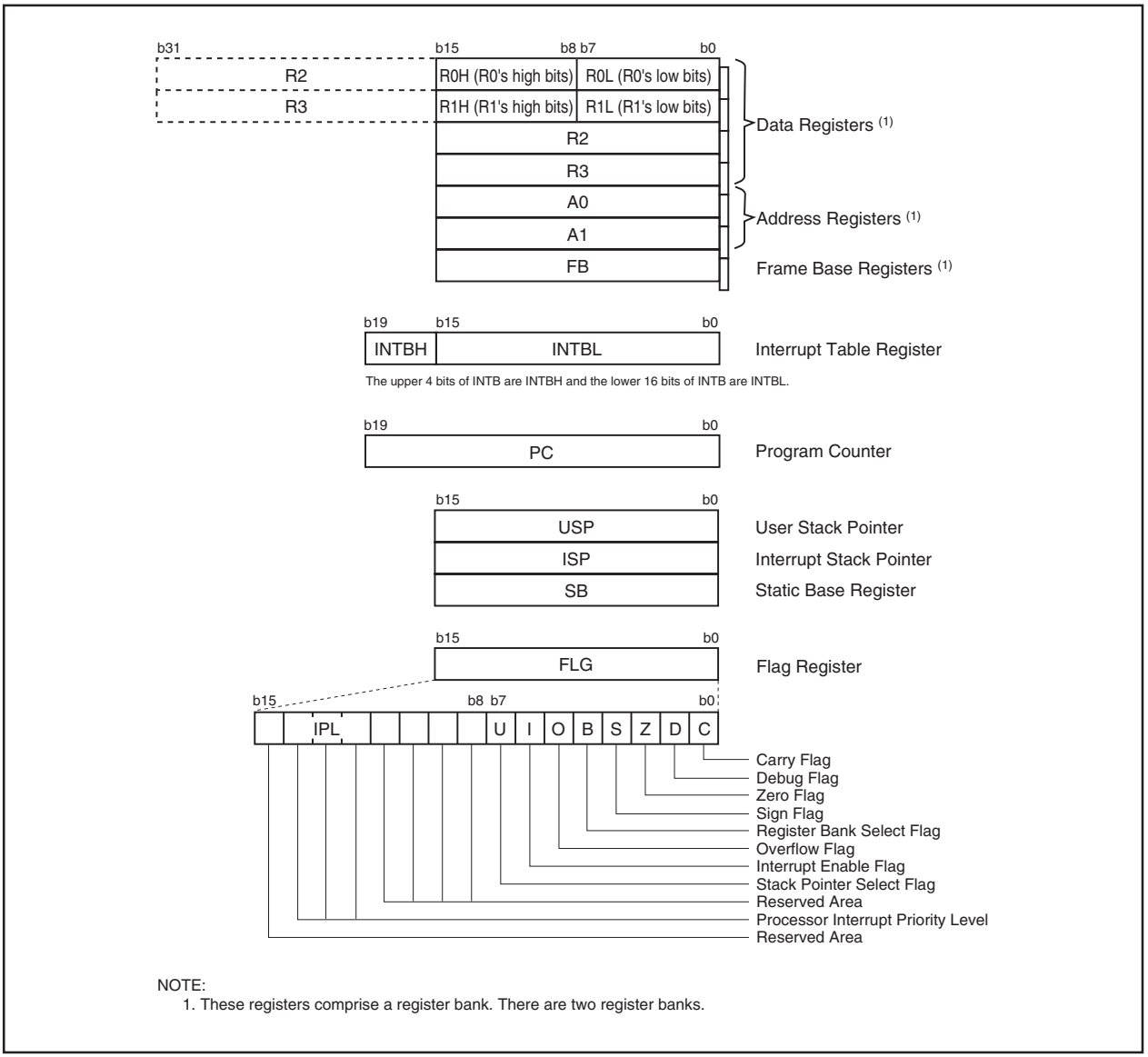


Figure 2.1 CPU Registers

2.1 Data Registers (R0, R1, R2, and R3)

The R0 register consists of 16 bits, and is used mainly for transfers and arithmetic/logic operations. R1 to R3 are the same as R0.

The R0 register can be separated between high (R0H) and low (R0L) for use as two 8-bit data registers. R1H and R1L are the same as R0H and R0L. Conversely R2 and R0 can be combined for use as a 32-bit data register (R2R0). R3R1 is analogous to R2R0.

2.2 Address Registers (A0 and A1)

The A0 register consists of 16 bits, and is used for address register indirect addressing and address register relative addressing. They also are used for transfers and arithmetic/logic operations. A1 is the same as A0.

In some instructions, A1 and A0 can be combined for use as a 32-bit address register (A1A0).

Table 4.6 SFR Information (6) [1]

Address	Register	Symbol	After Reset
0140h	CAN0 Message Box 14: Identifier /DLC		XXh
0141h			XXh
0142h			XXh
0143h			XXh
0144h			XXh
0145h			XXh
0146h	CAN0 Message Box 14: Data Field		XXh
0147h			XXh
0148h			XXh
0149h			XXh
014Ah			XXh
014Bh			XXh
014Ch			XXh
014Dh			XXh
014Eh	CAN0 Message Box 14: Time Stamp		XXh
014Fh			XXh
0150h	CAN0 Message Box 15: Identifier /DLC		XXh
0151h			XXh
0152h			XXh
0153h			XXh
0154h			XXh
0155h			XXh
0156h	CAN0 Message Box 15: Data Field		XXh
0157h			XXh
0158h			XXh
0159h			XXh
015Ah			XXh
015Bh			XXh
015Ch			XXh
015Dh			XXh
015Eh	CAN0 Message Box 15: Time Stamp		XXh
015Fh			XXh
0160h	CAN0 Global Mask Register	C0GMR	XXh
0161h			XXh
0162h			XXh
0163h			XXh
0164h			XXh
0165h			XXh
0166h	CAN0 Local Mask A Register	C0LMAR	XXh
0167h			XXh
0168h			XXh
0169h			XXh
016Ah			XXh
016Bh			XXh
016Ch	CAN0 Local Mask B Register	C0LMBR	XXh
016Dh			XXh
016Eh			XXh
016Fh			XXh
0170h			XXh
0171h			XXh
0172h			
0173h			
0174h			
0175h			
0176h			
0177h			
0178h			
0179h			
017Ah			
017Bh			
017Ch			
017Dh			
017Eh			
017Fh			

X: Undefined

NOTE:
1. Blank spaces are reserved. No access is allowed.

Table 4.12 SFR Information (12)

Address	Register	Symbol	After Reset
02C0h	CAN1 Message Box 6: Identifier / DLC		XXh
02C1h			XXh
02C2h			XXh
02C3h			XXh
02C4h			XXh
02C5h			XXh
02C6h	CAN1 Message Box 6: Data Field		XXh
02C7h			XXh
02C8h			XXh
02C9h			XXh
02CAh			XXh
02CBh			XXh
02CCh			XXh
02CDh			XXh
02CEh	CAN1 Message Box 6: Time Stamp		XXh
02CFh			XXh
02D0h	CAN1 Message Box 7: Identifier / DLC		XXh
02D1h			XXh
02D2h			XXh
02D3h			XXh
02D4h			XXh
02D5h			XXh
02D6h	CAN1 Message Box 7: Data Field		XXh
02D7h			XXh
02D8h			XXh
02D9h			XXh
02DAh			XXh
02DBh			XXh
02DCh			XXh
02DDh			XXh
02DEh	CAN1 Message Box 7: Time Stamp		XXh
02DFh			XXh
02E0h	CAN1 Message Box 8: Identifier / DLC		XXh
02E1h			XXh
02E2h			XXh
02E3h			XXh
02E4h			XXh
02E5h			XXh
02E6h	CAN1 Message Box 8: Data Field		XXh
02E7h			XXh
02E8h			XXh
02E9h			XXh
02EAh			XXh
02EBh			XXh
02ECh			XXh
02EDh			XXh
02EEh	CAN1 Message Box 8: Time Stamp		XXh
02EFh			XXh
02F0h	CAN1 Message Box 9: Identifier / DLC		XXh
02F1h			XXh
02F2h			XXh
02F3h			XXh
02F4h			XXh
02F5h			XXh
02F6h	CAN1 Message Box 9: Data Field		XXh
02F7h			XXh
02F8h			XXh
02F9h			XXh
02FAh			XXh
02FBh			XXh
02FCh			XXh
02FDh			XXh
02FEh	CAN1 Message Box 9: Time Stamp		XXh
02FFh			XXh

X: Undefined

Table 4.16 SFR Information (16) (2)

Address	Register	Symbol	After Reset
03C0h	A/D Register 0	AD0	XXh
03C1h			XXh
03C2h	A/D Register 1	AD1	XXh
03C3h			XXh
03C4h	A/D Register 2	AD2	XXh
03C5h			XXh
03C6h	A/D Register 3	AD3	XXh
03C7h			XXh
03C8h	A/D Register 4	AD4	XXh
03C9h			XXh
03CAh	A/D Register 5	AD5	XXh
03CBh			XXh
03CCh	A/D Register 6	AD6	XXh
03CDh			XXh
03CEh	A/D Register 7	AD7	XXh
03CFh			XXh
03D0h			
03D1h			
03D2h			
03D3h			
03D4h	A/D Control Register 2	ADCON2	00h
03D5h			
03D6h	A/D Control Register 0	ADCON0	00000XXXb
03D7h	A/D Control Register 1	ADCON1	00h
03D8h	D/A Register 0	DA0	00h
03D9h			
03DAh	D/A Register 1	DA1	00h
03DBh			
03DCh	D/A Control Register	DACON	00h
03DDh			
03DEh			
03DFh			
03E0h	Port P0 Register	P0	XXh
03E1h	Port P1 Register	P1	XXh
03E2h	Port P0 Direction Register	PD0	00h
03E3h	Port P1 Direction Register	PD1	00h
03E4h	Port P2 Register	P2	XXh
03E5h	Port P3 Register	P3	XXh
03E6h	Port P2 Direction Register	PD2	00h
03E7h	Port P3 Direction Register	PD3	00h
03E8h	Port P4 Register	P4	XXh
03E9h	Port P5 Register	P5	XXh
03EAh	Port P4 Direction Register	PD4	00h
03EBh	Port P5 Direction Register	PD5	00h
03ECh	Port P6 Register	P6	XXh
03EDh	Port P7 Register	P7	XXh
03EEh	Port P6 Direction Register	PD6	00h
03EFh	Port P7 Direction Register	PD7	00h
03F0h	Port P8 Register	P8	XXh
03F1h	Port P9 Register	P9	XXh
03F2h	Port P8 Direction Register	PD8	00X00000b
03F3h	Port P9 Direction Register	PD9	00h
03F4h	Port P10 Register	P10	XXh
03F5h			
03F6h	Port P10 Direction Register	PD10	00h
03F7h			
03F8h			
03F9h			
03FAh			
03FBh			
03FCh	Pull-up Control Register 0	PUR0	00h
03FDh	Pull-up Control Register 1	PUR1	00000000b (1) 00000010b
03FEh	Pull-up Control Register 2	PUR2	00h
03FFh	Port Control Register	PCR	00h

X: Undefined

NOTES:
1. At hardware reset, the register is as follows:
   - 00000000b where "L" is input to the CNVSS pin
   - 00000010b where "H" is input to the CNVSS pin

   At software reset, watchdog timer reset and oscillation stop detection reset, the register is as follows:
   - 00000000b where bits PM01 to PM00 in the PM0 register are 00b (single-chip mode)
   - 00000010b where bits PM01 to PM00 in the PM0 register are 01b (memory expansion mode) or 11b (microprocessor mode)
2. Blank spaces are reserved. No access is allowed.

5. Electrical Characteristics

5.1 Electrical Characteristics (T/V-ver.)

Table 5.1 Absolute Maximum Ratings

Symbol	Parameter		Condition	Rated Value	Unit
V_{CC}	Supply voltage (VCC1 = VCC2)		VCC = AVCC	–0.3 to 6.5	V
AV_{CC}	Analog supply voltage		VCC = AVCC	–0.3 to 6.5	V
V_I	Input voltage	$\overline{RESET}$, CNVSS, BYTE, P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_0, P7_2 to P7_7, P8_0 to P8_7, P9_0, P9_2 to P9_7, P10_0 to P10_7, VREF, XIN		–0.3 to VCC+0.3	V
		P7_1, P9_1		–0.3 to 6.5	V
V_O	Output voltage	P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_0, P7_2 to P7_7, P8_0 to P8_4, P8_6, P8_7, P9_0, P9_2 to P9_7, P10_0 to P10_7, XOUT		–0.3 to VCC+0.3	V
		P7_1, P9_1		–0.3 to 6.5	V
P_d	Power dissipation		Topr = 25°C	700	mW
T_{opr}	Operating ambient temperature	During MCU operation		T version: –40 to 85 V version: –40 to 125 (option)	°C
		During flash memory program and erase operation		0 to 60	
T_{stg}	Storage temperature			–65 to 150	°C

option: All options are on request basis.

Table 5.8 Power Supply Circuit Timing Characteristics

Symbol	Parameter	Measuring Condition	Standard			Unit
			Min.	Typ.	Max.	
$t_{d(P-R)}$	Time for internal power supply stabilization during powering-on	VCC = 4.2 to 5.5 V			2	ms
$t_{d(R-S)}$	STOP release time				150	µs
$t_{d(W-S)}$	Low power dissipation mode wait mode release time				150	µs

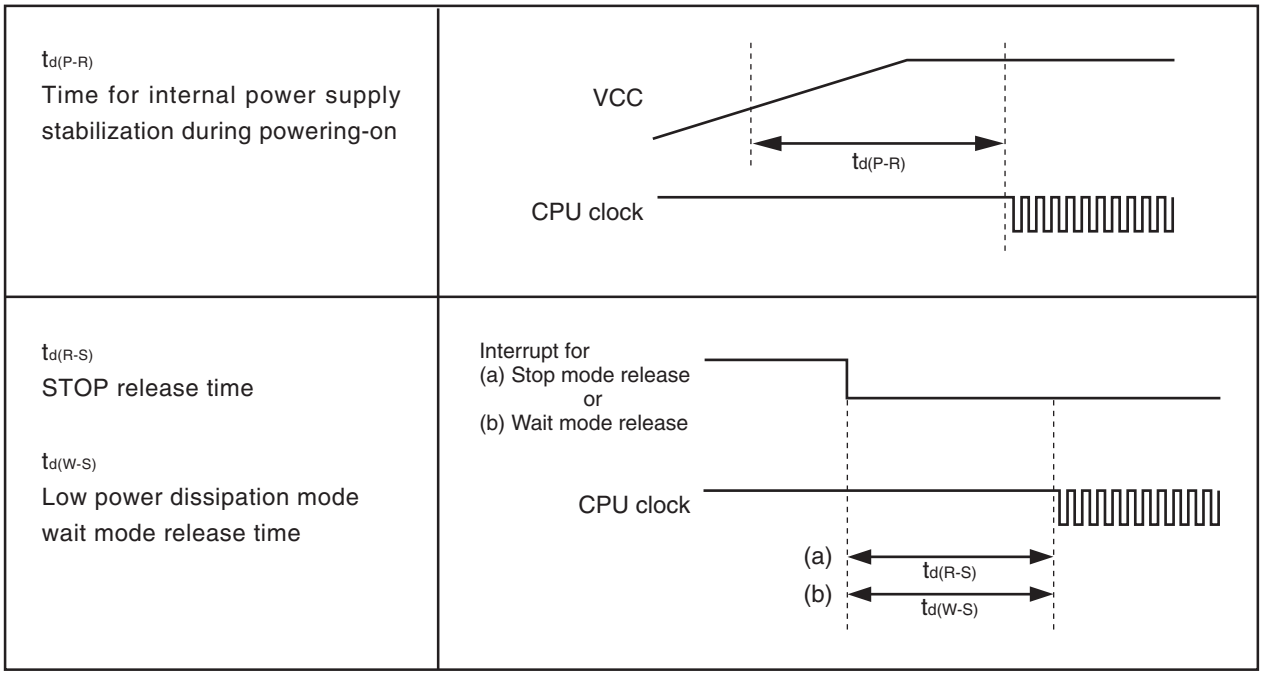


Figure 5.1 Power Supply Circuit Timing Diagram

Timing Requirements

VCC = 5 V

(Referenced to VCC = 5 V, VSS = 0 V, at Topr = –40 to 85°C unless otherwise specified)

Table 5.17 Timer B Input (Counter Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBiIN input cycle time (counted on one edge)	100		ns
$t_{w(TBH)}$	TBiIN input HIGH pulse width (counted on one edge)	40		ns
$t_{w(TBL)}$	TBiIN input LOW pulse width (counted on one edge)	40		ns
$t_{c(TB)}$	TBiIN input cycle time (counted on both edges)	200		ns
$t_{w(TBH)}$	TBiIN input HIGH pulse width (counted on both edges)	80		ns
$t_{w(TBL)}$	TBiIN input LOW pulse width (counted on both edges)	80		ns

Table 5.18 Timer B Input (Pulse Period Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBiIN input cycle time	400		ns
$t_{w(TBH)}$	TBiIN input HIGH pulse width	200		ns
$t_{w(TBL)}$	TBiIN input LOW pulse width	200		ns

Table 5.19 Timer B Input (Pulse Width Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBiIN input cycle time	400		ns
$t_{w(TBH)}$	TBiIN input HIGH pulse width	200		ns
$t_{w(TBL)}$	TBiIN input LOW pulse width	200		ns

Table 5.20 A/D Trigger Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(AD)}$	$\overline{\text{ADTRG}}$ input cycle time (trigger able minimum)	1000		ns
$t_{w(ADL)}$	$\overline{\text{ADTRG}}$ input LOW pulse width	125		ns

Table 5.21 Serial Interface

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CK)}$	CLKi input cycle time	200		ns
$t_{w(CKH)}$	CLKi input HIGH pulse width	100		ns
$t_{w(CKL)}$	CLKi input LOW pulse width	100		ns
$t_{d(C-Q)}$	TXDi output delay time		80	ns
$t_{h(C-Q)}$	TXDi hold time	0		ns
$t_{su(D-C)}$	RXDi input setup time	70		ns
$t_{h(C-D)}$	RXDi input hold time	90		ns

Table 5.22 External Interrupt $\overline{\text{INTi}}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(INH)}$	$\overline{\text{INTi}}$ input HIGH pulse width	250		ns
$t_{w(INL)}$	$\overline{\text{INTi}}$ input LOW pulse width	250		ns

Switching Characteristics VCC = 5 V

(Referenced to VCC = 5 V, VSS = 0 V, at Topr = –40 to 85 °C unless otherwise specified)

Table 5.24 Memory Expansion Mode and Microprocessor Mode (for 1- to 3-wait setting and external area access)

Symbol	Parameter	Measuring Condition	Standard		Unit
			Min.	Max.	
$t_{d(BCLK-AD)}$	Address output delay time	Figure 5.2		25	ns
$t_{h(BCLK-AD)}$	Address output hold time (in relation to BCLK)		4		ns
$t_{h(RD-AD)}$	Address output hold time (in relation to RD)		0		ns
$t_{h(WR-AD)}$	Address output hold time (in relation to WR)		(NOTE 1)		ns
$t_{d(BCLK-CS)}$	Chip select output delay time			25	ns
$t_{h(BCLK-CS)}$	Chip select output hold time (in relation to BCLK)		4		ns
$t_{d(BCLK-ALE)}$	ALE signal output delay time			15	ns
$t_{h(BCLK-ALE)}$	ALE signal output hold time		–4		ns
$t_{d(BCLK-RD)}$	RD signal output delay time			25	ns
$t_{h(BCLK-RD)}$	RD signal output hold time		0		ns
$t_{d(BCLK-WR)}$	WR signal output delay time			25	ns
$t_{h(BCLK-WR)}$	WR signal output hold time		0		ns
$t_{d(BCLK-DB)}$	Data output delay time (in relation to BCLK)			40	ns
$t_{h(BCLK-DB)}$	Data output hold time (in relation to BCLK) (3)		4		ns
$t_{d(DB-WR)}$	Data output delay time (in relation to WR)		(NOTE 2)		ns
$t_{h(WR-DB)}$	Data output hold time (in relation to WR) (3)		(NOTE 1)		ns
$t_{d(BCLK-HLDA)}$	$\overline{HLDA}$ output delay time			40	ns

NOTES:

1. Calculated according to the BCLK frequency as follows:

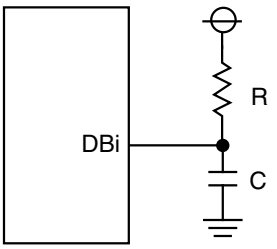
$$\frac{0.5 \times 10^9}{f(BCLK)} - 10 \text{ [ns]}$$

2. Calculated according to the BCLK frequency as follows:

$$\frac{(n - 0.5) \times 10^9}{f(BCLK)} - 40 \text{ [ns]}$$

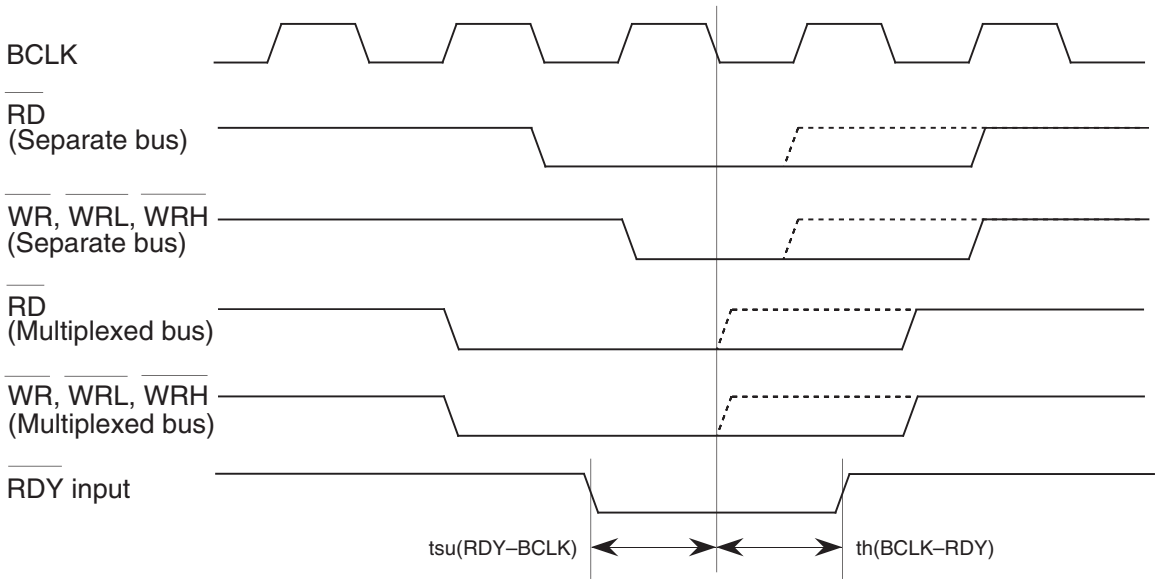
n is “1” for 1-wait setting, “2” for 2-wait setting and “3” for 3-wait setting. When n = 1, f(BCLK) is 12.5 MHz or less.

3. This standard value shows the timing when the output is off, and does not show hold time of data bus.
Hold time of data bus varies with capacitor volume and pull-up (pull-down) resistance value.
Hold time of data bus is expressed in
$t = -CR \times \ln (1 - V_{OL} / V_{CC})$
by a circuit of the right figure.
For example, when $V_{OL} = 0.2\ V_{CC}$, C = 30 pF, R =1 kΩ, hold time of output “L” level is
$t = -30\ pF \times 1\ k\Omega \times \ln (1 - 0.2\ V_{CC} / V_{CC}) = 6.7$ ns.

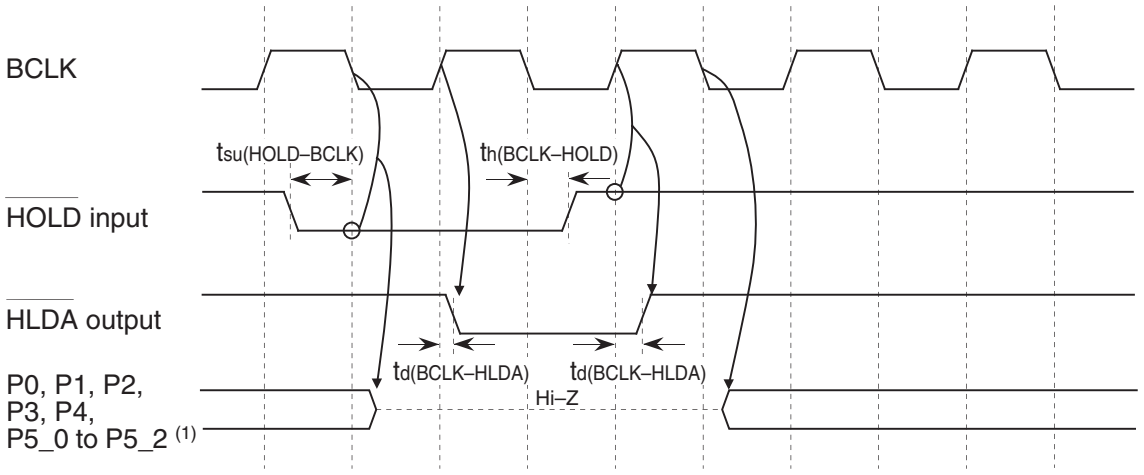


Memory Expansion Mode and Microprocessor Mode **VCC = 5 V**

(Effective for setting with wait)



(Common to setting with wait and setting without wait)



NOTE:
1. The above pins are set to high-impedance regardless of the input level of the BYTE pin, the PM06 bit in the PM0 register, and the PM11 bit in the PM1 register.

Measuring conditions :
- VCC = 5 V
- Input timing voltage : Determined with V_{IL} = 1.0 V, V_{IH} = 4.0 V
- Output timing voltage: Determined with V_{OL} = 2.5 V, V_{OH} = 2.5 V

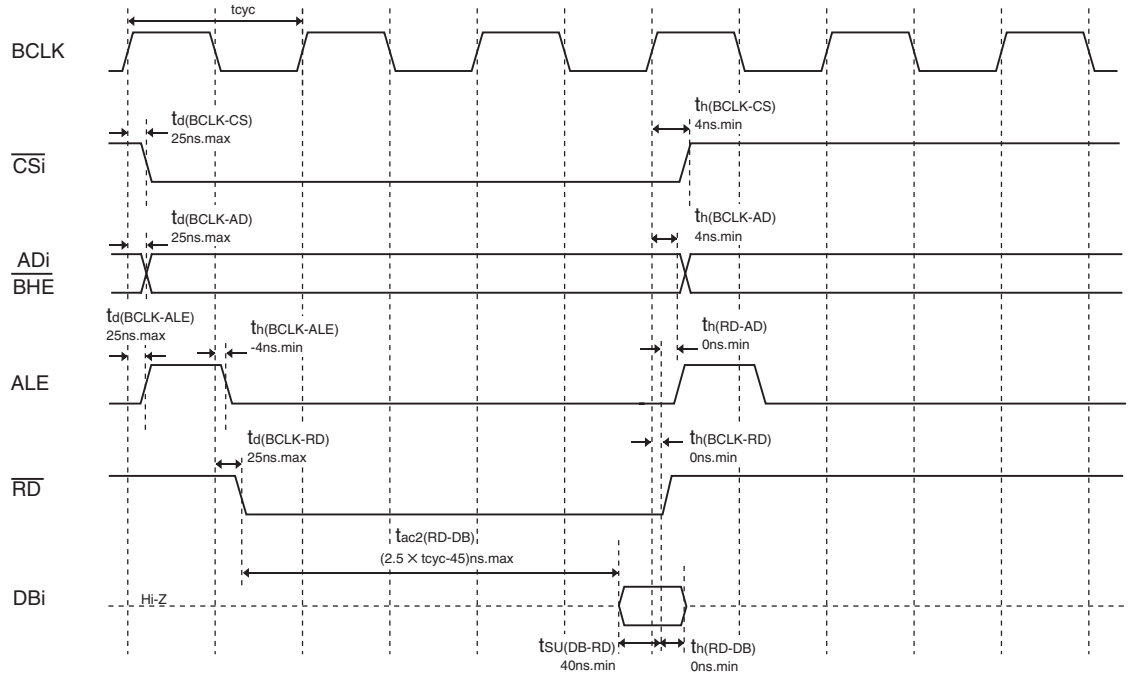
Figure 5.4 Timing Diagram (2)

Memory Expansion Mode and Microprocessor Mode

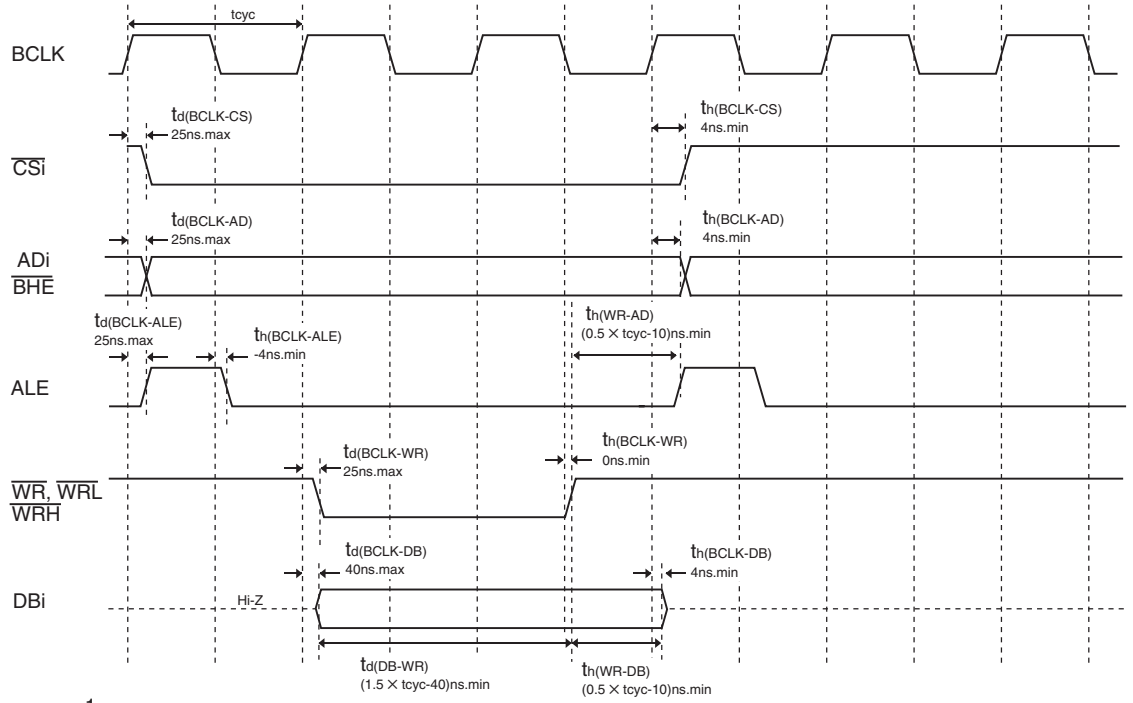
VCC = 5 V

(For 2-wait setting and external area access)

Read timing



Write timing



$$tcyc = \frac{1}{f(BCLK)}$$

Measuring conditions :

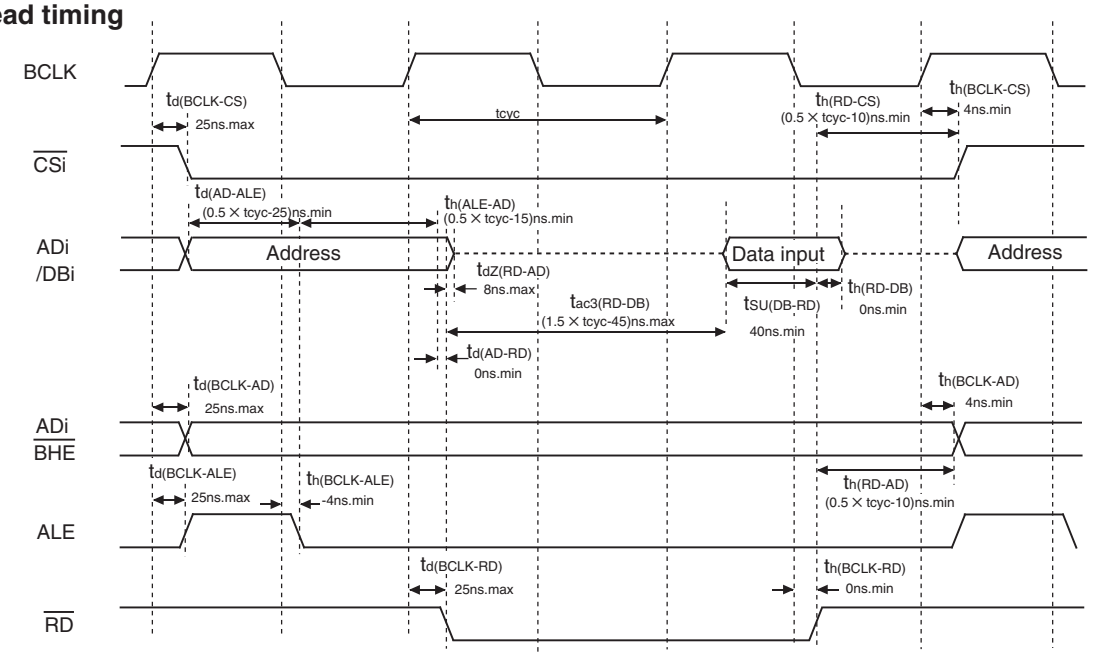
- VCC = 5 V
- Input timing voltage : V_{IL} = 0.8 V, V_{IH} = 2.0 V
- Output timing voltage : V_{OL} = 0.4 V, V_{OH} = 2.4 V

Figure 5.7 Timing Diagram (5)

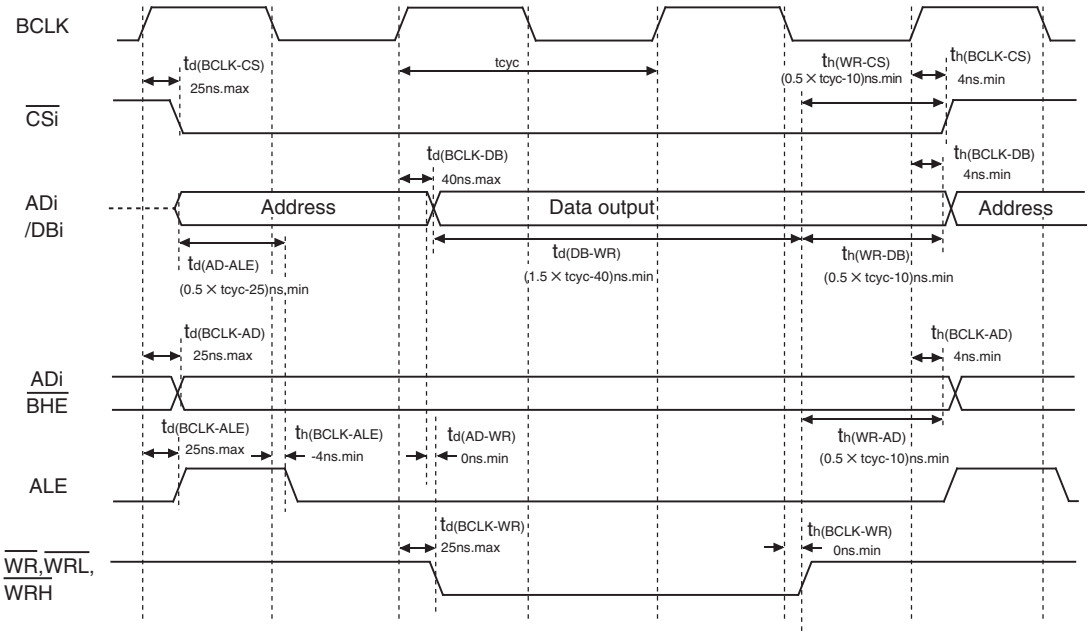
Memory Expansion Mode and Microprocessor Mode — VCC = 5 V

(For 1- or 2-wait setting, external area access and multiplexed bus selection)

Read timing



Write timing



$$tcyc = \frac{1}{f(BCLK)}$$

Measuring conditions :

- VCC = 5 V
- Input timing voltage : V_{IL} = 0.8 V, V_{IH} = 2.0 V
- Output timing voltage : V_{OL} = 0.4 V, V_{OH} = 2.4 V

Figure 5.9 Timing Diagram (7)

5.2 Electrical Characteristics (Normal-ver.)

Table 5.26 Absolute Maximum Ratings

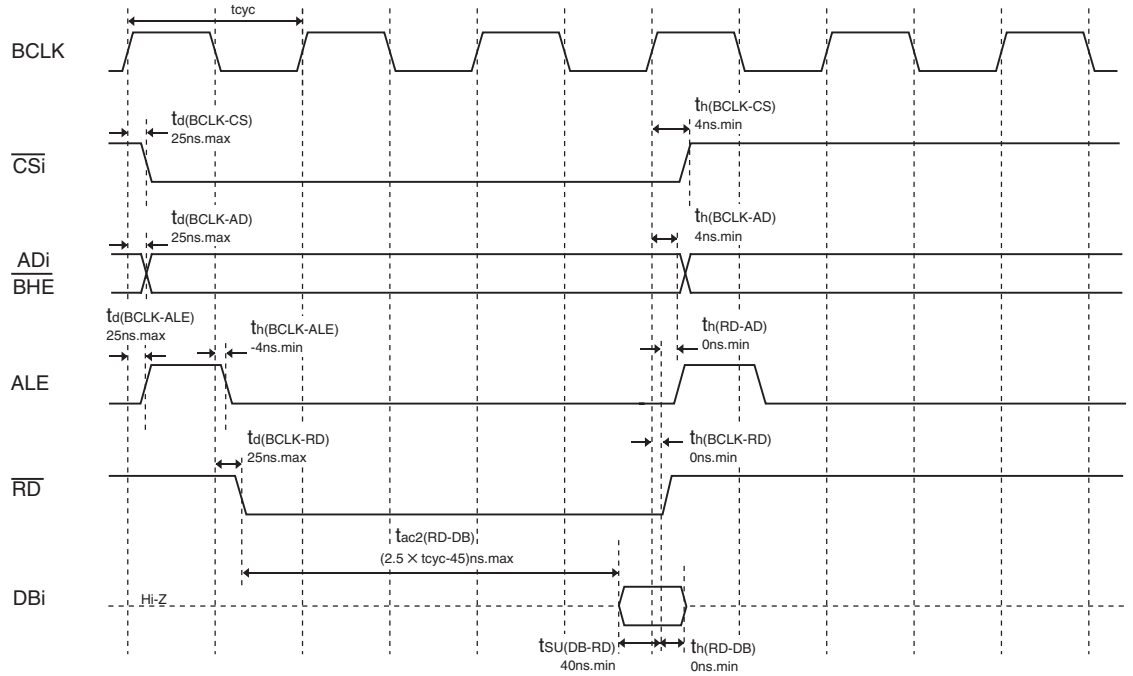
Symbol	Parameter		Condition	Rated Value	Unit
V_{CC}	Supply voltage (VCC1 = VCC2)		VCC = AVCC	–0.3 to 6.5	V
AV_{CC}	Analog supply voltage		VCC = AVCC	–0.3 to 6.5	V
V_I	Input voltage	$\overline{RESET}$, CNVSS, BYTE, P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_0, P7_2 to P7_7, P8_0 to P8_7, P9_0, P9_2 to P9_7, P10_0 to P10_7, VREF, XIN		–0.3 to VCC+0.3	V
		P7_1, P9_1		–0.3 to 6.5	V
V_O	Output voltage	P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_0, P7_2 to P7_7, P8_0 to P8_4, P8_6, P8_7, P9_0, P9_2 to P9_7, P10_0 to P10_7, XOUT		–0.3 to VCC+0.3	V
		P7_1, P9_1		–0.3 to 6.5	V
P_d	Power dissipation		Topr = 25°C	700	mW
T_{opr}	Operating ambient temperature	During MCU operation		–40 to 85	°C
		During flash memory program and erase operation		0 to 60	
T_{stg}	Storage temperature			–65 to 150	°C

Memory Expansion Mode and Microprocessor Mode

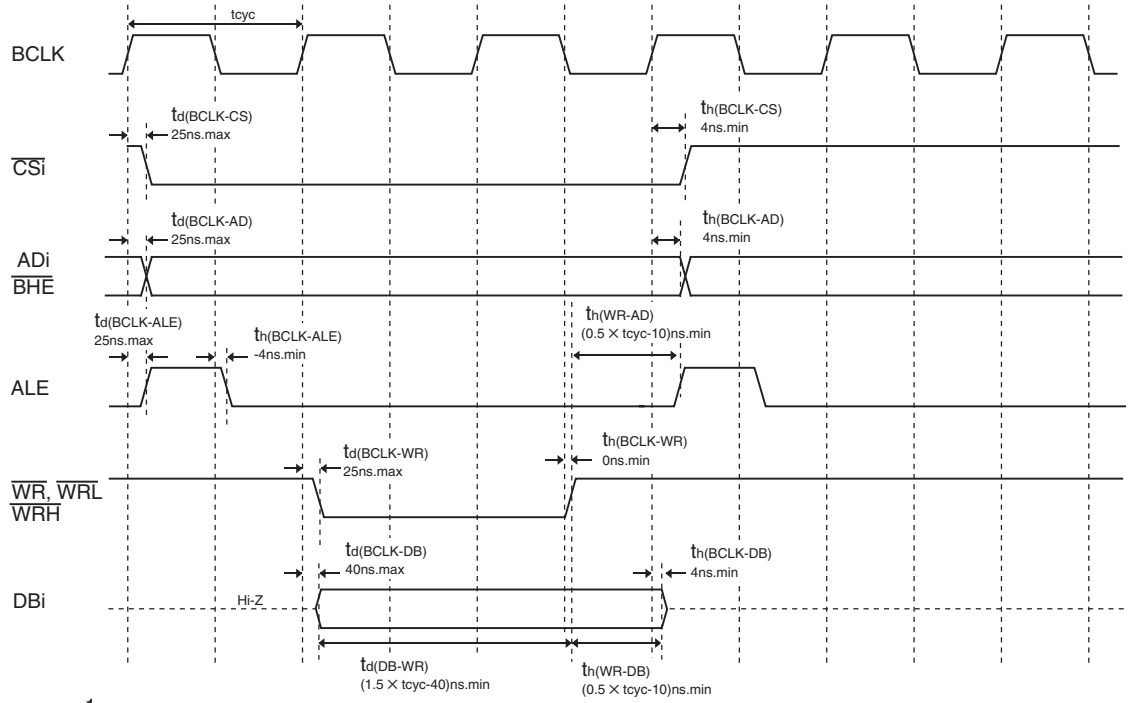
VCC = 5 V

(For 2-wait setting and external area access)

Read timing



Write timing



$$tcyc = \frac{1}{f(BCLK)}$$

Measuring conditions :

- VCC = 5 V
- Input timing voltage : V_{IL} = 0.8 V, V_{IH} = 2.0 V
- Output timing voltage : V_{OL} = 0.4 V, V_{OH} = 2.4 V

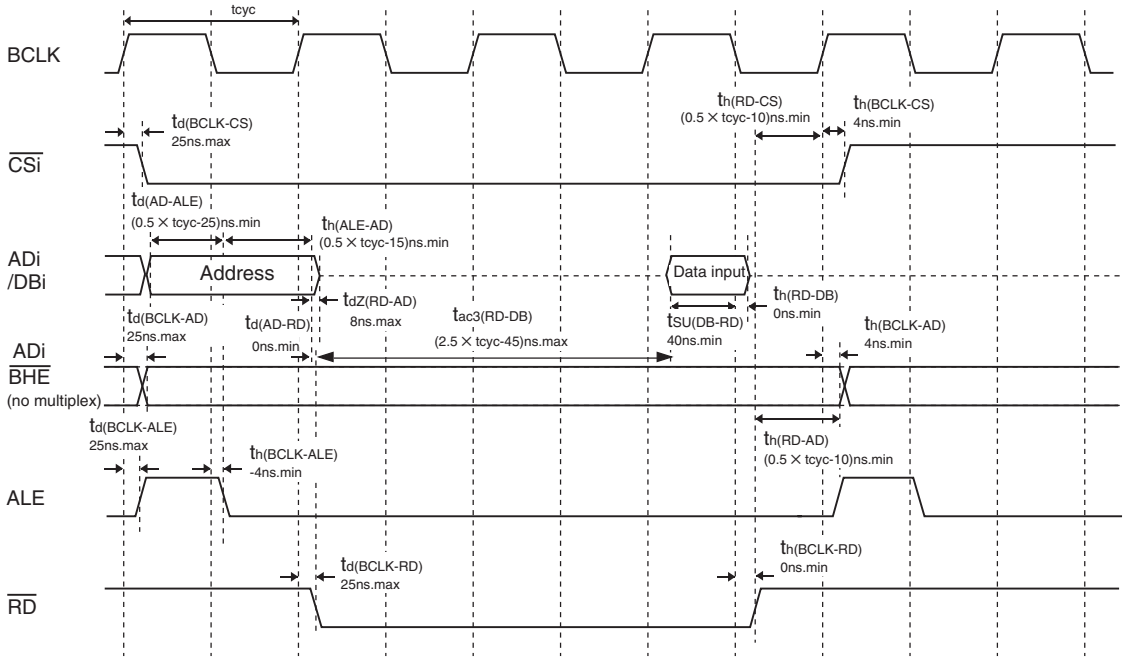
Figure 5.17 Timing Diagram (5)

Memory Expansion Mode and Microprocessor Mode

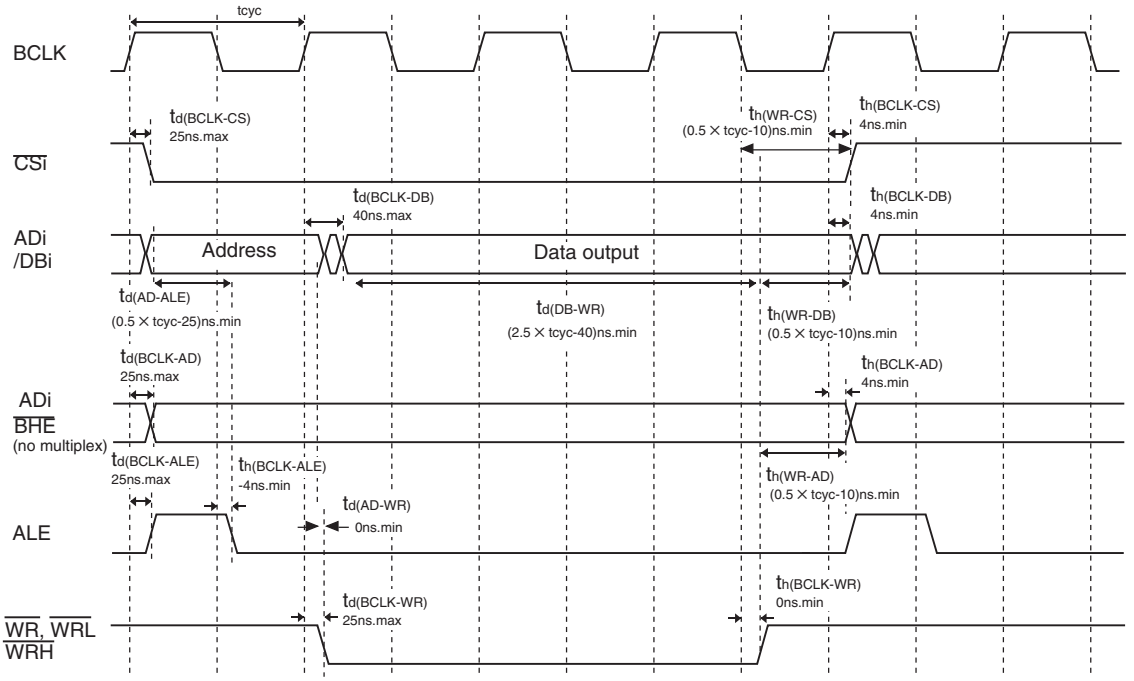
VCC = 5 V

(For 3-wait setting, external area access and multiplexed bus selection)

Read timing



Write timing



$$tcyc = \frac{1}{f(BCLK)}$$

Measuring conditions :

- VCC = 5 V
- Input timing voltage : V_{IL} = 0.8 V, V_{IH} = 2.0 V
- Output timing voltage : V_{OL} = 0.4 V, V_{OH} = 2.4 V

Figure 5.20 Timing Diagram (8)

Timing Requirements

VCC = 3.3 V

(Referenced to VCC = 3.3 V, VSS = 0 V, at Topr = –40 to 85°C unless otherwise specified)

Table 5.60 Timer B Input (Counter Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBiIN input cycle time (counted on one edge)	150		ns
$t_{w(TBH)}$	TBiIN input HIGH pulse width (counted on one edge)	60		ns
$t_{w(TBL)}$	TBiIN input LOW pulse width (counted on one edge)	60		ns
$t_{c(TB)}$	TBiIN input cycle time (counted on both edges)	300		ns
$t_{w(TBH)}$	TBiIN input HIGH pulse width (counted on both edges)	120		ns
$t_{w(TBL)}$	TBiIN input LOW pulse width (counted on both edges)	120		ns

Table 5.61 Timer B Input (Pulse Period Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBiIN input cycle time	600		ns
$t_{w(TBH)}$	TBiIN input HIGH pulse width	300		ns
$t_{w(TBL)}$	TBiIN input LOW pulse width	300		ns

Table 5.62 Timer B Input (Pulse Width Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBiIN input cycle time	600		ns
$t_{w(TBH)}$	TBiIN input HIGH pulse width	300		ns
$t_{w(TBL)}$	TBiIN input LOW pulse width	300		ns

Table 5.63 A/D Trigger Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(AD)}$	$\overline{\text{ADTRG}}$ input cycle time (trigger able minimum)	1500		ns
$t_{w(ADL)}$	$\overline{\text{ADTRG}}$ input LOW pulse width	200		ns

Table 5.64 Serial Interface

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CK)}$	CLKi input cycle time	300		ns
$t_{w(CKH)}$	CLKi input HIGH pulse width	150		ns
$t_{w(CKL)}$	CLKi input LOW pulse width	150		ns
$t_{d(C-Q)}$	TXDi output delay time		160	ns
$t_{h(C-Q)}$	TXDi hold time	0		ns
$t_{su(D-C)}$	RXDi input setup time	100		ns
$t_{h(C-D)}$	RXDi input hold time	90		ns

Table 5.65 External Interrupt $\overline{\text{INTi}}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(INH)}$	$\overline{\text{INTi}}$ input HIGH pulse width	380		ns
$t_{w(INL)}$	$\overline{\text{INTi}}$ input LOW pulse width	380		ns

Switching Characteristics

VCC = 3.3 V

(Referenced to VCC = 3.3 V, VSS = 0 V, at Topr = –40 to 85 °C unless otherwise specified)

Table 5.67 Memory Expansion Mode and Microprocessor Mode (for 1- to 3-wait setting and external area access)

Symbol	Parameter	Measuring Condition	Standard		Unit
			Min.	Max.	
$t_{d(BCLK-AD)}$	Address output delay time	Figure 5.21		30	ns
$t_{h(BCLK-AD)}$	Address output hold time (in relation to BCLK)		4		ns
$t_{h(RD-AD)}$	Address output hold time (in relation to RD)		0		ns
$t_{h(WR-AD)}$	Address output hold time (in relation to WR)		(NOTE 1)		ns
$t_{d(BCLK-CS)}$	Chip select output delay time			30	ns
$t_{h(BCLK-CS)}$	Chip select output hold time (in relation to BCLK)		4		ns
$t_{d(BCLK-ALE)}$	ALE signal output delay time			25	ns
$t_{h(BCLK-ALE)}$	ALE signal output hold time		–4		ns
$t_{d(BCLK-RD)}$	RD signal output delay time			30	ns
$t_{h(BCLK-RD)}$	RD signal output hold time		0		ns
$t_{d(BCLK-WR)}$	WR signal output delay time			30	ns
$t_{h(BCLK-WR)}$	WR signal output hold time		0		ns
$t_{d(BCLK-DB)}$	Data output delay time (in relation to BCLK)			40	ns
$t_{h(BCLK-DB)}$	Data output hold time (in relation to BCLK) (3)		4		ns
$t_{d(DB-WR)}$	Data output delay time (in relation to WR)		(NOTE 2)		ns
$t_{h(WR-DB)}$	Data output hold time (in relation to WR) (3)		(NOTE 1)		ns
$t_{d(BCLK-HLDA)}$	$\overline{HLDA}$ output delay time			40	ns

NOTES:

1. Calculated according to the BCLK frequency as follows:

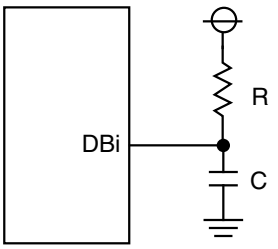
$$\frac{0.5 \times 10^9}{f(BCLK)} - 10 \text{ [ns]}$$

2. Calculated according to the BCLK frequency as follows:

$$\frac{(n - 0.5) \times 10^9}{f(BCLK)} - 40 \text{ [ns]}$$

n is “1” for 1-wait setting, “2” for 2-wait setting and “3” for 3-wait setting. When n = 1, f(BCLK) is 12.5 MHz or less.

3. This standard value shows the timing when the output is off, and does not show hold time of data bus.
Hold time of data bus varies with capacitor volume and pull-up (pull-down) resistance value.
Hold time of data bus is expressed in
$t = -CR \times \ln (1 - V_{OL} / V_{CC})$
by a circuit of the right figure.
For example, when $V_{OL} = 0.2\ V_{CC}$, C = 30 pF, R =1 kΩ, hold time of output “L” level is
$t = -30\ pF \times 1\ k\Omega \times \ln (1 - 0.2\ V_{CC} / V_{CC}) = 6.7$ ns.

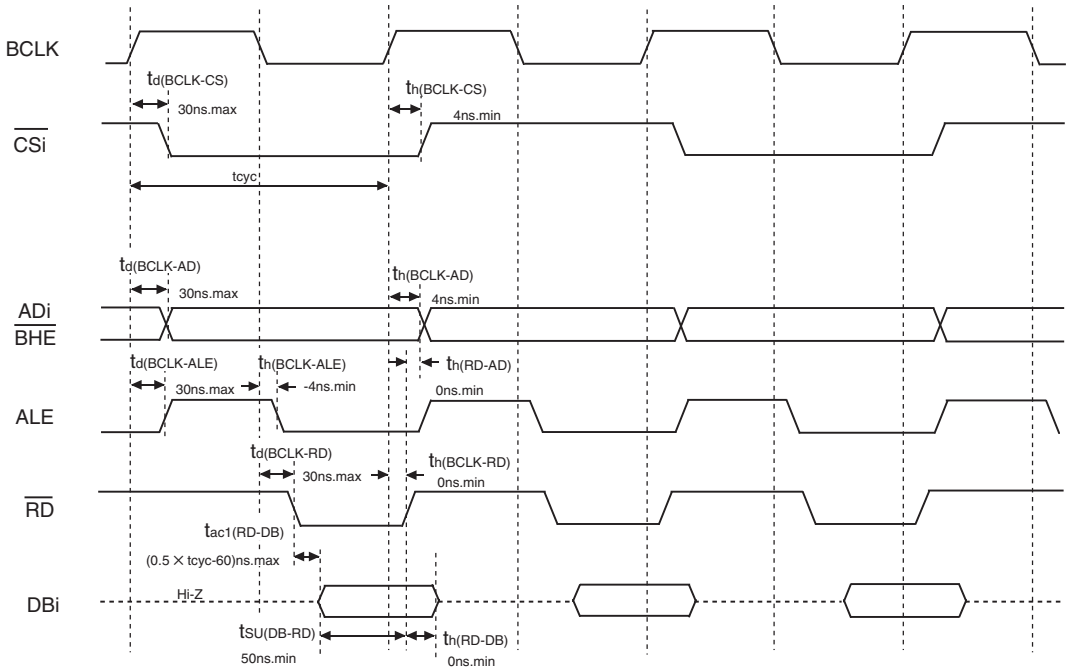


Memory Expansion Mode and Microprocessor Mode

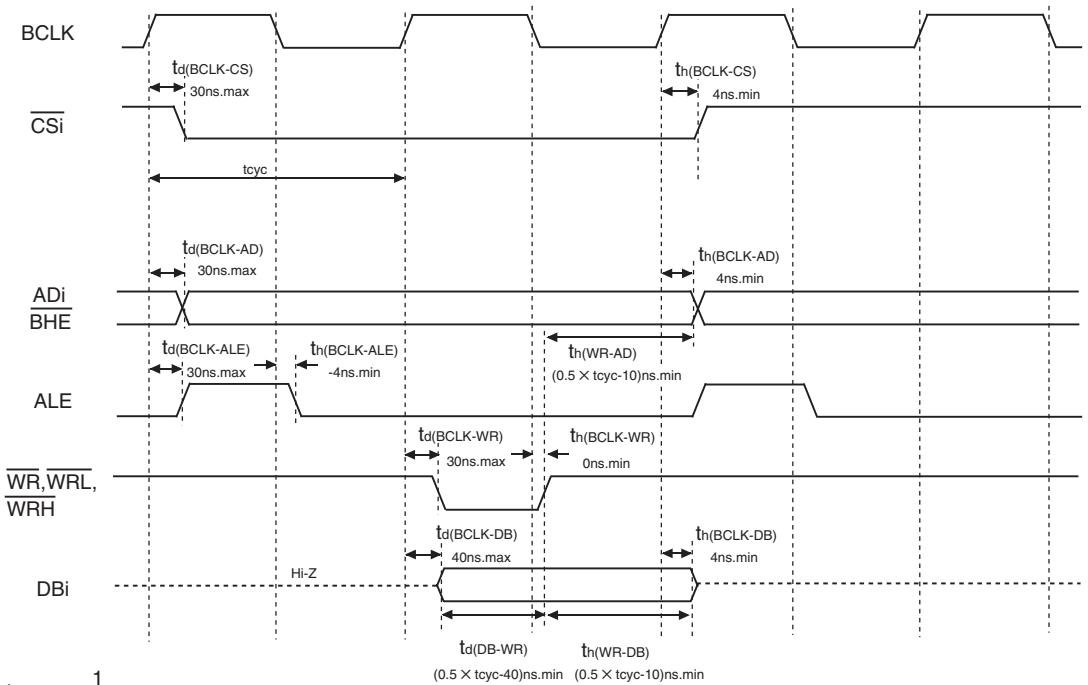
VCC = 3.3 V

(For setting with no wait)

Read timing



Write timing



$$tcyc = \frac{1}{f(BCLK)}$$

Measuring conditions :

- VCC = 3.3 V
- Input timing voltage : V_{IL} = 0.6 V, V_{IH} = 2.7 V
- Output timing voltage : V_{OL} = 1.65 V, V_{OH} = 1.65 V

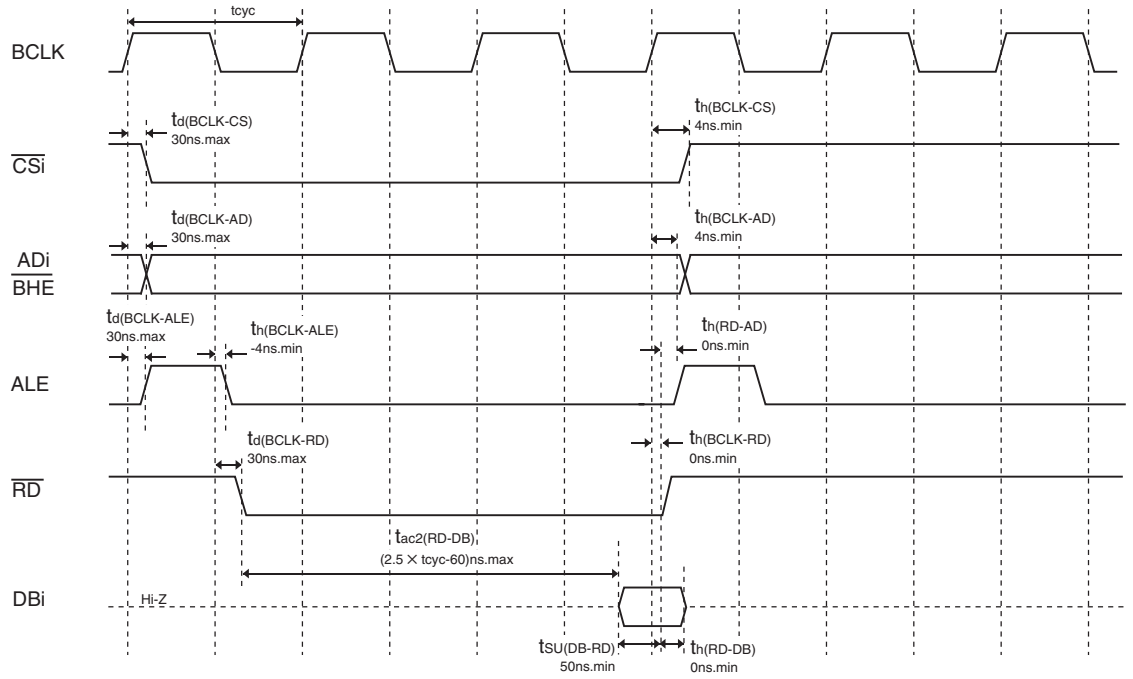
Figure 5.24 Timing Diagram (3)

Memory Expansion Mode and Microprocessor Mode

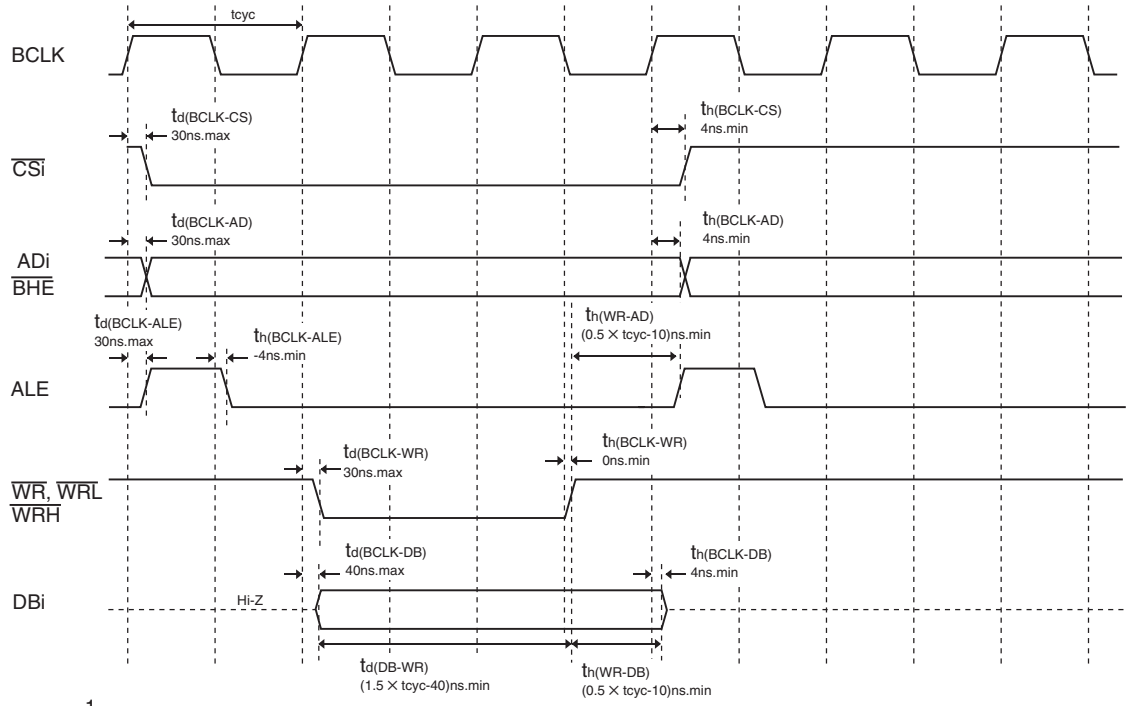
VCC = 3.3 V

(For 2-wait setting and external area access)

Read timing



Write timing



$$tcyc = \frac{1}{f(BCLK)}$$

Measuring conditions :

- VCC = 3.3 V
- Input timing voltage : V_{IL} = 0.6 V, V_{IH} = 2.7 V
- Output timing voltage : V_{OL} = 1.65 V, V_{OH} = 1.65 V

Figure 5.26 Timing Diagram (5)